TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HC11AP,TC74HC11AF,TC74HC11AFN

Triple 3-Input AND Gate

The TC74HC11A is a high speed CMOS 3-INPUT AND GATE fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

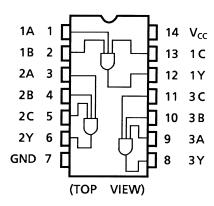
The internal circuit is composed of 4 stages including a buffer output, which provide high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

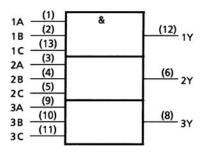
Features

- High speed: $t_{pd} = 7 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $ICC = 1 \mu A \text{ (max)}$ at $Ta = 25^{\circ}C$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: | IOH | = IOL = 4 mA (min)
- Balanced propagation delays: $t_pLH \simeq t_pHL$
- Wide operating voltage range: V_{CC} (opr) = 2 to 6 V
- Pin and function compatible with 74LS11

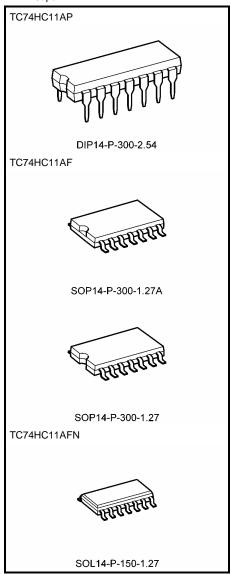
Pin Assignment



IEC Logic Symbol



Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

 DIP14-P-300-2.54
 : 0.96 g (typ.)

 SOP14-P-300-1.27A
 : 0.18 g (typ.)

 SOP14-P-300-1.27
 : 0.18 g (typ.)

 SOL14-P-150-1.27
 : 0.12 g (typ.)



Truth Table

Α	В	С	Υ
L	Χ	Х	L
Х	L	Х	L
Х	Х	L	L
Н	Н	Н	Н

X: Don't care

Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	–0.5 to 7	V
DC input voltage	V _{IN}	-0.5 to V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5 to V _{CC} + 0.5	V
Input diode current	l _{IK}	±20	mA
Output diode current	I _{OK}	±20	mA
DC output current	lout	±25	mA
DC V _{CC} /ground current	I _{CC}	±50	mA
Power dissipation	P _D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C shall be applied until 300 mW.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2 to 6	V
Input voltage	V _{IN}	0 to V _{CC}	V
Output voltage	V _{OUT}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
		0 to 1000 (V _{CC} = 2.0 V)	
Input rise and fall time	t _r , t _f	0 to 500 (V _{CC} = 4.5 V)	ns
		0 to 400 (V _{CC} = 6.0 V)	

Note: The recommended operating conditions are required to ensure the normal operation of the device.
Unused inputs must be tied to either VCC or GND.

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Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
	-,			V _{CC} (V)	Min	Тур.	Max	Min	Max	
		V _{IH} —		2.0	1.50	_	_	1.50	_	
High-level input voltage	V_{IH}			4.5	3.15	_	_	3.15	_	V
ŭ				6.0	4.20	_	_	4.20	_	
				2.0		_	0.50	_	0.50	
Low-level input voltage	V_{IL}	_		4.5	_	_	1.35	_	1.35	V
Ü				6.0	_	_	1.80	_	1.80	
	Voн	V _{IN} = V _{IH} or V _{IL}		2.0	1.9	2.0	_	1.9	_	
			$I_{OH} = -20 \mu A$	4.5	4.4	4.5	_	4.4	_	
High-level output voltage				6.0	5.9	6.0	_	5.9	_	V
Ŭ			$I_{OH} = -4 \text{ mA}$	4.5	4.18	4.31		4.13		
			$I_{OH} = -5.2 \text{ mA}$	6.0	5.68	5.80	_	5.63	_	
		VIN = VIH or VIL		2.0	_	0.0	0.1	_	0.1	
			$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1	_	0.1	
Low-level output voltage	V_{OL}			6.0	_	0.0	0.1	_	0.1	V
			I _{OL} = 4 mA	4.5	_	0.17	0.26	_	0.33	
			$I_{OL} = 5.2 \text{ mA}$	6.0	_	0.18	0.26	_	0.33	
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	_	_	±0.1		±1.0	μА
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	_	_	1.0	_	10.0	μА

AC Characteristics (C_L = 15 pF, V_{CC} = 5 V, Ta = 25°C, input: t_r = t_f = 6 ns)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Output transition time	t _{TLH}	_	_	4	8	ns
Propagation delay time	t _{pLH} t _{pHL}			7	14	ns



AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit
		V _{CC} (V)	Min	Тур.	Max	Min	Max		
	t		2.0	_	25	75	_	95	
Output transition time	t _{TLH}	_	4.5	_	7	15	_	19	ns
	t _{THL}		6.0	_	6	13	_	16	
			2.0	_	30	85	_	105	
Propagation delay time	t _{pLH}	_	4.5	_	10	17	_	21	ns
	t _{pHL}		6.0	_	9	14	_	18	
Input capacitance	C _{IN}	_		_	5	10	_	10	pF
Power dissipation capacitance	C _{PD} (Note)	_		_	32	_	_	_	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

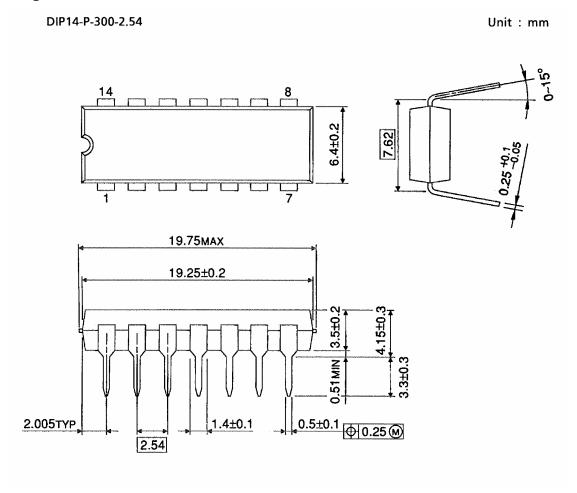
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Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$ (per gate)



Package Dimensions

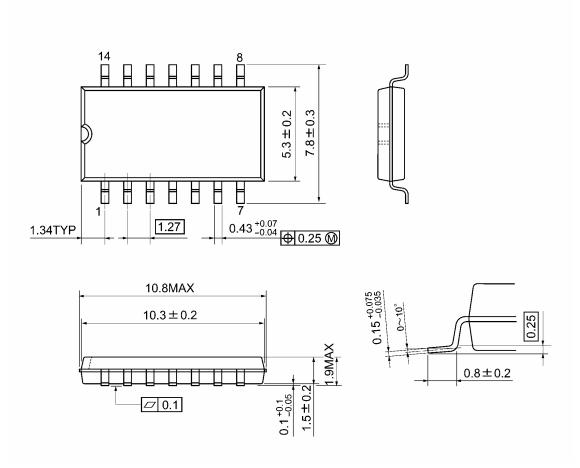


Weight: 0.96 g (typ.)

Package Dimensions

TOSHIBA

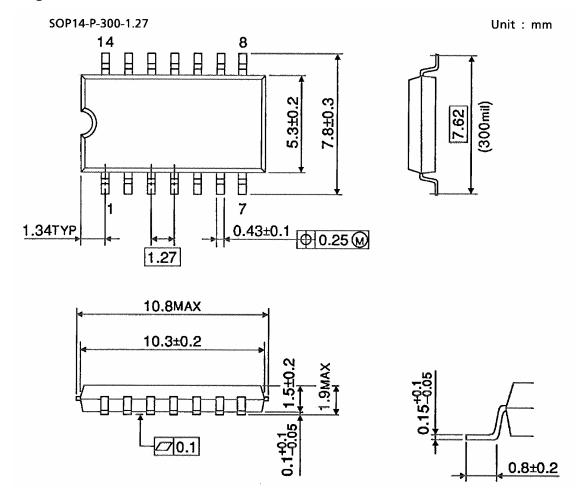
SOP14-P-300-1.27A Unit: mm



Weight: 0.18 g (typ.)



Package Dimensions

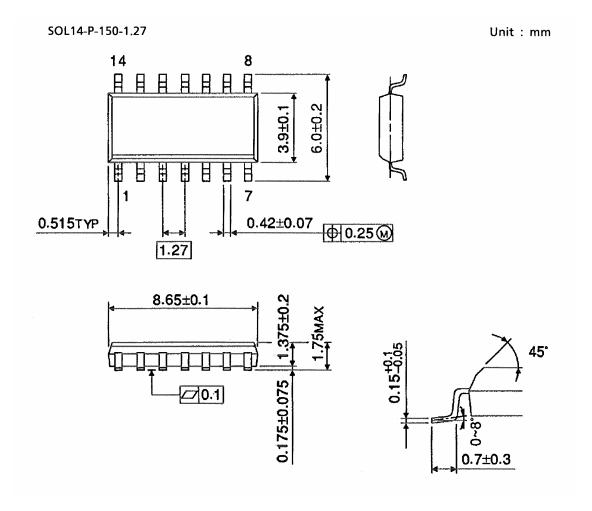


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Weight: 0.18 g (typ.)



Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Note: Lead (Pb)-Free Packages

DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27

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